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# Switch-mode Power Rectifier 60 V, 30 A

### **Features and Benefits**

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capability
- 30 A Total (15 A Per Diode Leg)
- Guard-Ring for Stress Protection
- These Devices are Pb-Free and are RoHS Compliant

## **Applications**

- Power Supply Output Rectification
- Power Management
- Instrumentation

### **Mechanical Characteristics:**

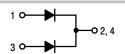
- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight (Approximately): 1.9 Grams (TO-220 & TO-220FP)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



ON Semiconductor®

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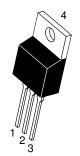
# SCHOTTKY BARRIER RECTIFIER 30 AMPERES, 60 VOLTS



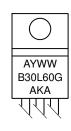
TO-220

CASE 221A

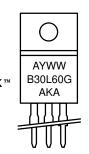
STYLE 6



MARKING DIAGRAMS







= Assembly Location

Y = Year
WW = Work Week
B30L60 = Device Code
G = Pb-Free Device
AKA = Polarity Designator

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

# MAXIMUM RATINGS (Per Diode Leg)

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	60	V
Average Rectified Forward Current MBR30L60CTG (Rated $V_R$ ) $T_C$ = 133°C MBRF30L60CTG (Rated $V_R$ ) $T_C$ = 108°C	(Per Leg) (Per Device) (Per Device)	I <sub>F(AV)</sub>	15 30	Α
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I <sub>FSM</sub>	240	А
Operating Junction Temperature (Note 1)		TJ	-55 to +150	°C
Storage Temperature		T <sub>stg</sub>	-65 to +175	°C
ESD Ratings:	Machine Model = C Human Body Model = 3B		> 400 > 8000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance MBR30L60CTG  Junction-to-Case Junction-to-Ambient MBRF30L60CTG  Junction-to-Case Junction-to-Case Junction-to-Case Junction-to-Ambient	R <sub>θ</sub> JC R <sub>θ</sub> JA R <sub>θ</sub> JC R <sub>θ</sub> JA	2.1 70 5.0 75	°C/W

# **ELECTRICAL CHARACTERISTICS** (Per Diode Leg)

Characteristic	Symbol	Тур	Max	Unit
$\label{eq:maximum Instantaneous Forward Voltage (Note 2)} \begin{array}{c} \text{(I}_F = 15 \text{ A, T}_C = 25^\circ\text{C)} \\ \text{(I}_F = 15 \text{ A, T}_C = 125^\circ\text{C)} \\ \text{(I}_F = 30 \text{ A, T}_C = 25^\circ\text{C)} \\ \text{(I}_F = 30 \text{ A, T}_C = 125^\circ\text{C)} \\ \end{array}$	VF	0.57 0.53 0.75 0.70	0.62 0.57 0.81 0.73	٧
Maximum Instantaneous Reverse Current (Note 2) (Rated DC Voltage, $T_C$ = 25°C) (Rated DC Voltage, $T_C$ = 125°C)	i <sub>R</sub>	137 62	350 110	μ <b>A</b> mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

# **DEVICE ORDERING INFORMATION**

Device Order Number	Package Type	Shipping
MBR30L60CTG	TO-220 (Pb-Free)	50 Units / Rail
MBRF30L60CTG	TO-220FP (Pb-Free)	50 Units / Rail

<sup>1.</sup> The heat generated must be less than the thermal conductivity from Junction–to–Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

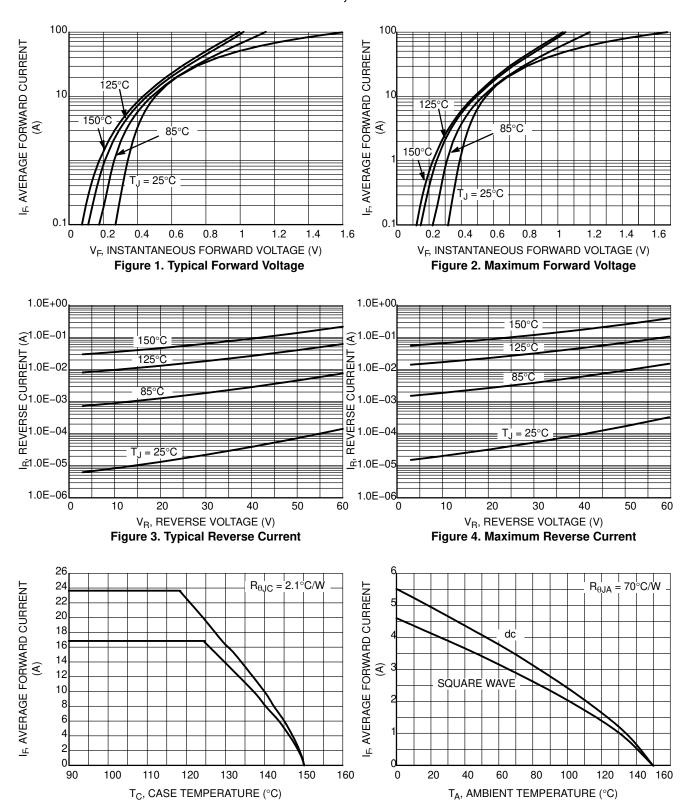


Figure 5. Current Derating, Case per Leg MBR30L60CT

Figure 6. Current Derating, Ambient per Leg MBR30L60CT

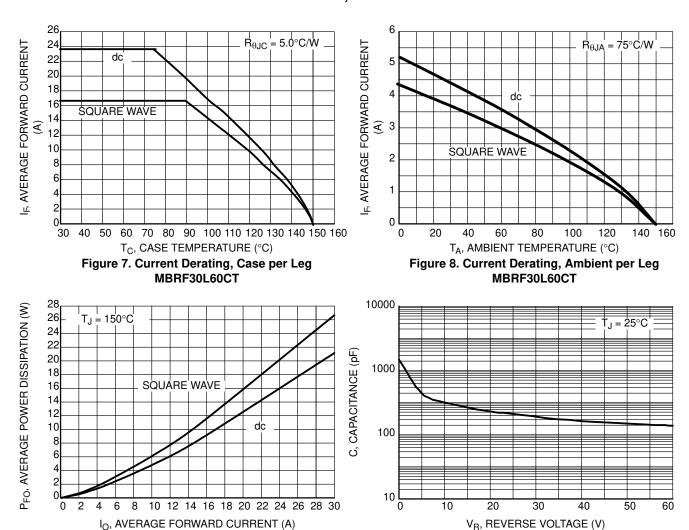


Figure 9. Forward Power Dissipation

Figure 10. Capacitance

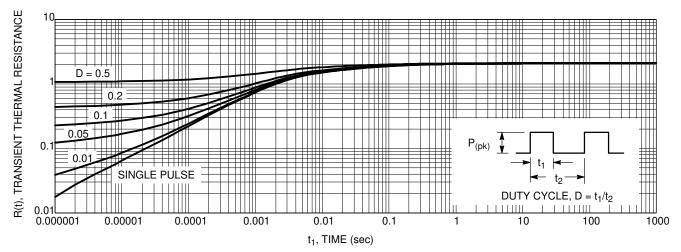


Figure 11. Thermal Response Junction-to-Case, per Leg for MBR30L60CT

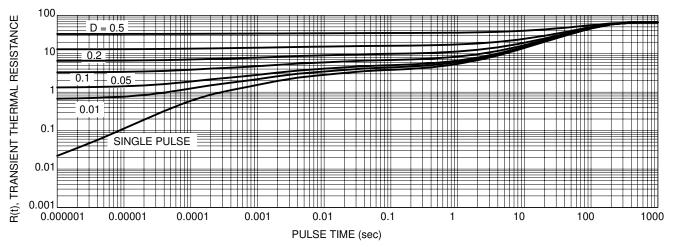


Figure 12. Thermal Response Junction-to-Ambient, per Leg for MBR30L60CT

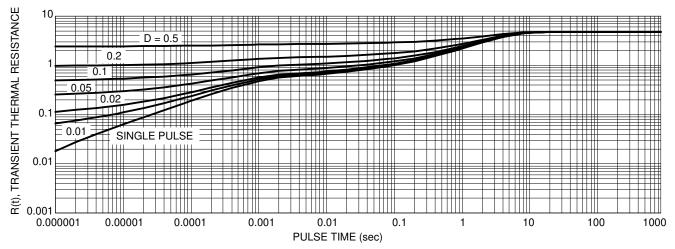


Figure 13. Thermal Response Junction-to-Case, per Leg for MBRF30L60CT

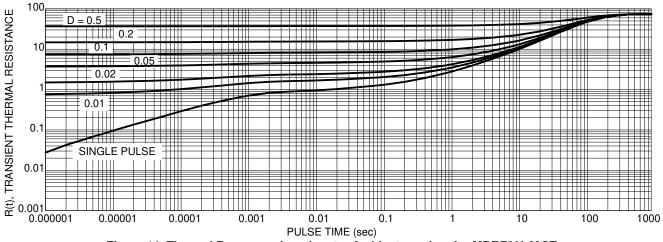
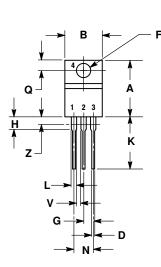
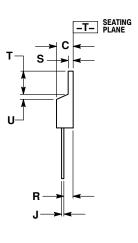


Figure 14. Thermal Response Junction-to-Ambient, per Leg for MBRF30L60CT

# **PACKAGE DIMENSIONS**

TO-220 CASE 221A-09 **ISSUE AH** 





- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

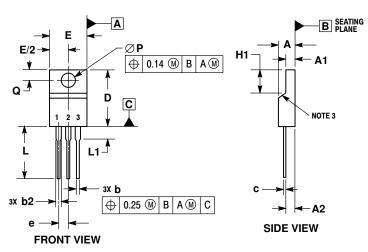
	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.415	9.66	10.53
С	0.160	0.190	4.07	4.83
D	0.025	0.038	0.64	0.96
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.161	2.80	4.10
J	0.014	0.024	0.36	0.61
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

- STYLE 6:
  PIN 1. ANODE
  2. CATHODE
  3. ANODE
  4. CATHODE

#### PACKAGE DIMENSIONS

# TO-220 FULLPACK, 3-LEAD

CASE 221AH ISSUE F



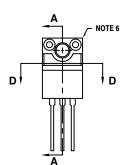
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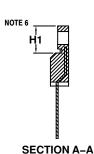
- DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS.
  3. CONTOUR UNCONTROLLED IN THIS AREA.
- S. OMMOGO ON TO ELD MITHS AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY.

   S. DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION.
- DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION.
   LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.
   CONTOURS AND FEATURES OF THE MOLDED PACKAGE BODY
- CONTOURS AND FEATURES OF THE MOLDED PACKAGE BODY MAY VARY WITHIN THE ENVELOP DEFINED BY DIMENSIONS AT AND H1 FOR MANUFACTURING PURPOSES.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.30	4.70	
A1	2.50	2.90	
A2	2.50	2.90	
b	0.54	0.84	
b2	1.10	1.40	
u	0.49	0.79	
D	14.70	15.30	
Е	9.70	10.30	
е	2.54 BSC		
H1	6.60	7.10	
L	12.50	14.73	
L1		2.80	
P	3.00	3.40	
Q	2.80	3.20	







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